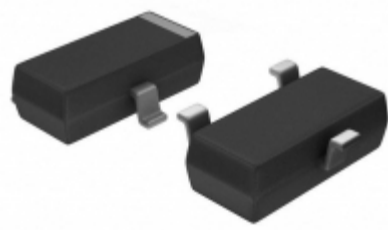
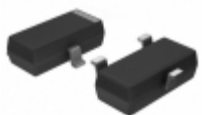


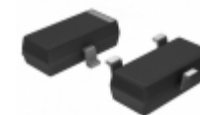




	<h2 style="color: red;">FJV3107RMTF</h2>
	<p><b>Hersteller-Teilenummer:</b> FJV3107RMTF</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> TRANS PREBIAS NPN 200MW SOT23-3</p> <p><b>Datenblätter:</b> <a href="#">1.FJV3107RMTF.pdf</a> <a href="#">2.FJV3107RMTF.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 38600 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FJV3107RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	38600 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	22 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FJV3107RMTF ist neu im Original, Suche FJV3107RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3107RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3107RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <b>FJV3108RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3109RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3107RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3105RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3
 <b>FJV3105RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3104RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3108RMTF</b> Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3	 <b>FJV3106RMTF</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3

### heiße Teile

Mehr

⊗ FJV1845EMTF	↔ FJV1845EMTF	⇒ FJV1845FMTF	D FJV1845FMTF	⇒ FJV1845PMTF
⊣ FJV1845PMTF	⊗ FJV1845UMTF	D FJV1845UMTF	⇒ FJV3101RLIMTF	⇒ FJV3101RMTF
⊗ FJV3101RMTF	⊣ FJV3102RMTF	⊗ FJV3102RMTF	↔ FJV3103RMTF	⇒ FJV3103RMTF
D FJV3104RMTF	⊗ FJV3104RMTF	⊣ FJV3105RMTF	⊗ FJV3105RMTF	⇒ FJV3106RMTF
⇒ FJV3106RMTF	↔ FJV3107RMTF	⊗ FJV3108RMTF	⊣ FJV3108RMTF	⇒ FJV3109R
↔ FJV3109RMTF	⇒ FJV3109RMTF	D FJV3110RMTF	⊗ FJV3110RMTF	⊣ FJV3111RMTF
⊗ FJV3111RMTF	D FJV3112RMTF	⇒ FJV3112RMTF	↔ FJV3113RMTF	⇒ FJV3113RMTF
⊣ FJV3114RMTF	⊗ FJV3114RMTF	↔ FJV3115RMTF	⇒ FJV3115RMTF	⇒ FJV4101RMTF
⊗ FJV4101RMTF	⊣ FJV4102RLIMTF	⊗ FJV4102RMTF	D FJV4102RMTF	⇒ FJV4103RMTF
↔ FJV4103RMTF	⊗ FJV4104RMTF	⊣ FJV4104RMTF	⊗ FJV4105RMTF	⇒ FJV4105RMTF

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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